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### STL86N3LLH6AG

# Automotive-grade N-channel 30 V, 4 mΩ typ., 80 A STripFET™ H6 Power MOSFET in a PowerFLAT™ 5x6 package

Datasheet - production data

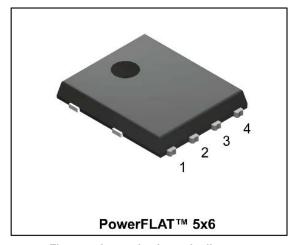
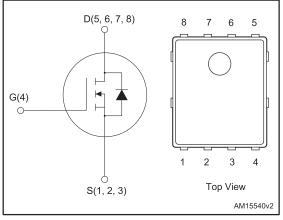


Figure 1: Internal schematic diagram



### **Features**

Order code	V <sub>DS</sub>	R <sub>DS(on)</sub> max.	ID
STL86N3LLH6AG	30 V	5.2 mΩ	80 A



- AEC-Q101 qualified
- Very low on-resistance
- Very low gate charge
- High avalanche ruggedness
- Low gate drive power loss
- Logic level
- Wettable flank package

### **Applications**

• Switching applications

### **Description**

This device is an N-channel Power MOSFET developed using the STripFET™ H6 technology with a new trench gate structure. The resulting Power MOSFET exhibits very low R<sub>DS(on)</sub> in all packages.

Table 1: Device summary

Order code	Marking	Package	Packing
STL86N3LLH6AG	86N3LLH6	PowerFLAT <sup>™</sup> 5x6	Tape and reel

Contents STL86N3LLH6AG

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STL86N3LLH6AG Electrical ratings

# 1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V <sub>DS</sub>	Drain-source voltage	30	V	
V <sub>GS</sub>	Gate-source voltage	± 20	V	
I <sub>D</sub> <sup>(1)</sup>	Drain current (continuous) at T <sub>C</sub> = 25 °C	80	Α	
I <sub>D</sub> <sup>(1)</sup>	Drain current (continuous) at T <sub>C</sub> = 70 °C	60		
I <sub>D</sub> <sup>(1)</sup>	Drain current (continuous) at T <sub>C</sub> = 100 °C	51	Α	
I <sub>DM</sub> <sup>(1)</sup> , <sup>(2)</sup>	Drain current (pulsed)	320	Α	
I <sub>D</sub> <sup>(3)</sup>	Drain current (continuous) at T <sub>pcb</sub> = 25 °C	21	Α	
I <sub>D</sub> <sup>(3)</sup>	Drain current (continuous) at T <sub>pcb</sub> = 70 °C	15.7	Α	
I <sub>D</sub> (3)	Drain current (continuous) at T <sub>pcb</sub> = 100 °C	13.1	Α	
I <sub>DM</sub> <sup>(2)</sup> , <sup>(3)</sup>	Drain current (pulsed)	84	Α	
P <sub>TOT</sub> <sup>(1)</sup>	Total dissipation at T <sub>C</sub> = 25 °C	60	10/	
P <sub>TOT</sub> <sup>(3)</sup>	Total dissipation at T <sub>pcb</sub> = 25 °C	4	W	
T <sub>stg</sub>	Storage temperature range	55 to 150	°C	
Tj	Operating junction temperature range	- 55 to 150 °		

### Notes:

Table 3: Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case	2.08	°C/W
R <sub>thj-pcb</sub> <sup>(1)</sup>	R <sub>thj-pcb</sub> <sup>(1)</sup> Thermal resistance junction-pcb		C/VV

### Notes:

 $^{(1)}$ When mounted on FR-4 board of 1 inch², 2oz Cu, t < 10 s

 $<sup>\</sup>ensuremath{^{(1)}}$  The value is rated according to  $R_{thj\text{-c}}.$ 

<sup>&</sup>lt;sup>(2)</sup>Pulse width limited by safe operating area.

 $<sup>\</sup>ensuremath{^{(3)}} The value is rated according to <math display="inline">R_{thj\text{-pcb}}.$ 

### 2 Electrical characteristics

(T<sub>C</sub> = 25 °C unless otherwise specified)

Table 4: On/off-states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)DSS</sub>	Drain-source breakdown voltage	V <sub>GS</sub> = 0, I <sub>D</sub> = 1 mA	30			>
	Zero gate voltage	V <sub>GS</sub> = 0, V <sub>DS</sub> = 30 V			1	
I <sub>DSS</sub>	drain current	V <sub>GS</sub> = 0, V <sub>DS</sub> = 30 V, T <sub>C</sub> = 125 °C			10	μA
I <sub>GSS</sub>	Gate-body leakage current	V <sub>DS</sub> = 0, V <sub>GS</sub> = ± 20 V			±100	nA
V <sub>GS(th)</sub>	Gate threshold voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1	1.7	2.5	V
D	Static drain-source on-	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10.5 A		4	5.2	mΩ
R <sub>DS(on)</sub>	resistance	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10.5 A		6.7	7.6	mΩ

Table 5: Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Ciss	Input capacitance		1350	1690	2030	pF
Coss	Output capacitance	V <sub>DS</sub> = 25 V, f = 1 MHz,	230	290	350	pF
Crss	Reverse transfer capacitance	V <sub>GS</sub> = 0	140	176	210	pF
Qg	Total gate charge	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 21 A,	-	17	-	nC
Qgs	Gate-source charge	V <sub>GS</sub> = 4.5 V	-	8	1	nC
$Q_{gd}$	Gate-drain charge	(see Figure 14: "Test circuit for gate charge bahavior")	-	6	-	nC
R <sub>G</sub>	Gate input resistance	f = 1 MHz, Gate DC Bias = 0, Test signal level = 20 mV open drain, ID = 0	1.25	1.7	1.2	Ω

Table 6: Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub>	Turn-on delay time	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 10.5 A,	-	9.5	1	ns
tr	Rise time	$R_G = 4.7 \Omega, V_{GS} = 10 V$	-	30	-	ns
t <sub>d(off)</sub>	Turn-off delay time	See Figure 13: "Test circuit for resistive load switching times"	-	37	-	ns
t <sub>f</sub>	Fall time	and Figure 18: "Switching times" waveform"	-	12	ı	ns

Table 7: Source-drain diode

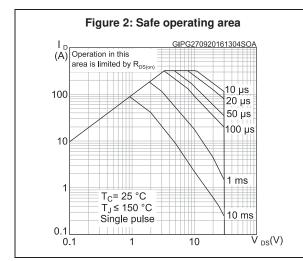
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>SD</sub>	Source-drain current		-		21	Α
I <sub>SDM</sub> <sup>(1)</sup>	Source-drain current (pulsed)		-		84	Α
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	I <sub>SD</sub> = 21 A, V <sub>GS</sub> = 0	-		1.1	>
t <sub>rr</sub>	Reverse recovery time	I <sub>SD</sub> = 10.5 A, di/dt = 100 A/μs	-	24		ns
Qrr	Reverse recovery charge	V <sub>DD</sub> = 25 V See Figure 15: "Test circuit for industry load switching and diado.	-	16.8		nC
I <sub>RRM</sub>	Reverse recovery current	inductive load switching and diode recovery times"		1.4		Α

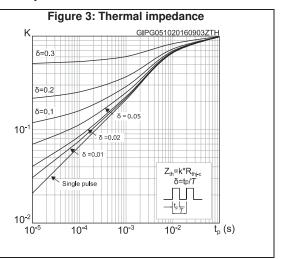
### Notes:

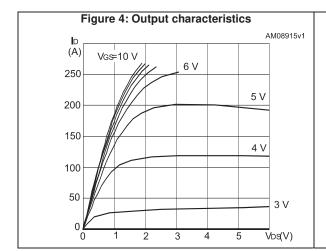
<sup>(1)</sup>Pulse width limited by safe operating area.

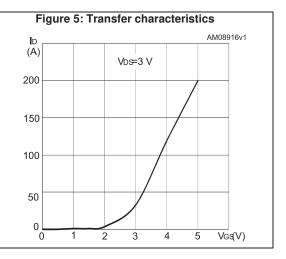
 $<sup>^{(2)}</sup>$ Pulsed: pulse duration = 300  $\mu$ s, duty cycle 1.5%.

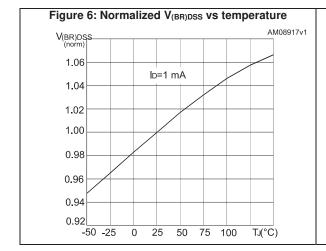
## 2.2 Electrical characteristics (curves)

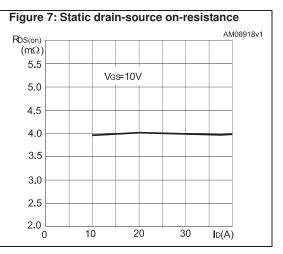


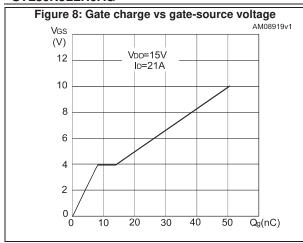












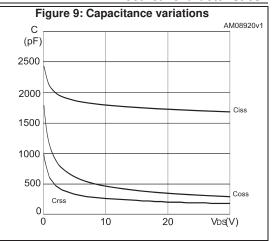


Figure 10: Normalized gate threshold voltage vs temperature

VGS(th)
(norm)

1.2

1.0

0.8

0.6

0.4

0.2

-50 -25 0 25 50 75 100 TJ(°C)

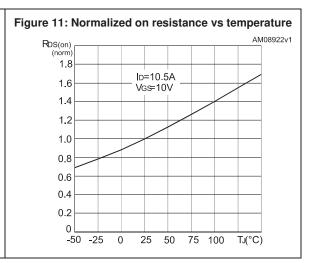
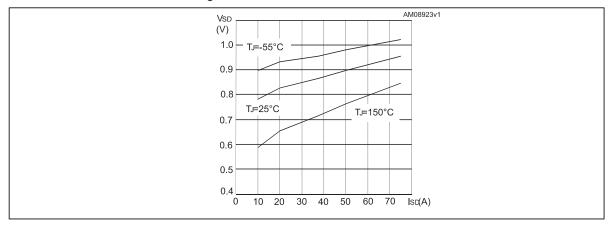


Figure 12: Source-drain diode forward characteristics



Test circuits STL86N3LLH6AG

#### 3 **Test circuits**

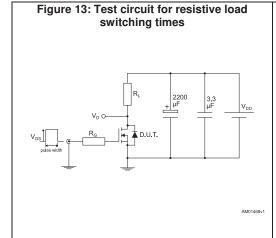


Figure 14: Test circuit for gate charge behavior 1 kΩ ±100 nF I<sub>G</sub>= CONST <del>-</del> O+ 2.7 kΩ 47 kΩ

Figure 15: Test circuit for inductive load switching and diode recovery times

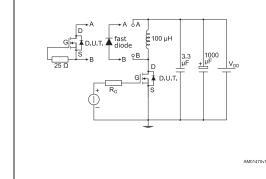


Figure 16: Unclamped inductive load test circuit

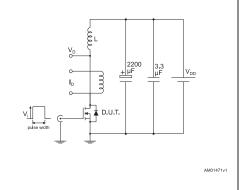


Figure 17: Unclamped inductive waveform

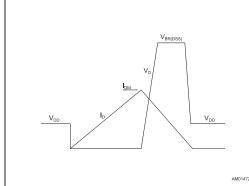
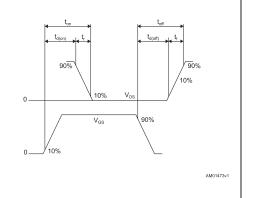


Figure 18: Switching time waveform



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#### 4 **Package information**

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

#### PowerFLAT™5x6 WF type R package information 4.1

BOTTOM VIEW D3 5 6 E6 E4(x4) E3 E3 Detail A Scale 3: 0.08 L(x4) b(x8) D5(x4) D4 SIDF VIFW ΑJ Detail A ŏ

Figure 19: PowerFLAT™ 5x6 WF type R package outline

A0Y5\_8231817\_R\_WF\_Rev\_14

Table 8: PowerFLAT™ 5x6 WF type R mechanical data

Table 8: PowerFLAT™ 5x6 WF type R mechanical data				
Dim.		mm		
Dilli.	Min.	Тур.	Max.	
А	0.80		1.00	
A1	0.02		0.05	
A2		0.25		
b	0.30		0.50	
С	5.80	6.00	6.10	
D	5.00	5.20	5.40	
D2	4.15		4.45	
D3	4.05	4.20	4.35	
D4	4.80	5.00	5.10	
D5	0.25	0.4	0.55	
D6	0.15	0.3	0.45	
е		1.27		
E	6.20	6.40	6.60	
E2	3.50		3.70	
E3	2.35		2.55	
E4	0.40		0.60	
E5	0.08		0.28	
E6	0.20	0.325	0.45	
E7	0.85	1.00	1.15	
E9	4.00	4.20	4.40	
E10	3.55	3.70	3.85	
К	1.275		1.575	
L	0.725	0.825	0.925	
L1	0.175	0.275	0.375	
θ	0°		12°	

0.65 (x4)

-1.27

3.81

-3.40

-4.60

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-6.5

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Figure 20: PowerFLAT™ 5x6 recommended footprint (dimensions are in mm)

Package information STL86N3LLH6AG

# 4.2 PowerFLAT™ 5x6 WF packing information

Figure 21: PowerFLAT™ 5x6 WF tape (dimensions are in mm)

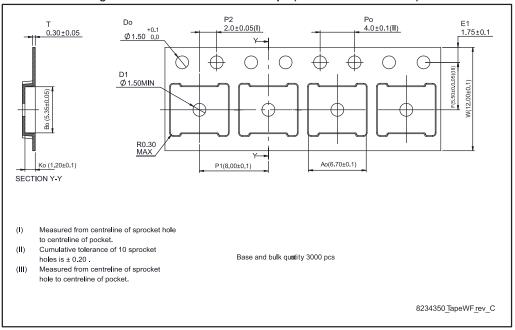
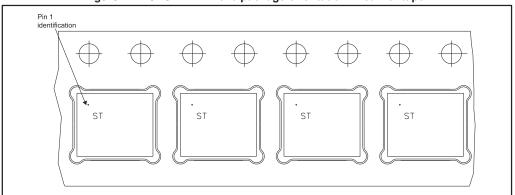


Figure 22: PowerFLAT™ 5x6 package orientation in carrier tape



PART NO.

R25.00

All dimensions are in millimeters

CORE DETAIL

8234350\_Reel\_rev\_C

Figure 23: PowerFLAT™ 5x6 reel (dimensions are in mm)

Revision history STL86N3LLH6AG

# 5 Revision history

Table 9: Document revision history

Date	Revision	Changes
26-Sep-2014	1	First release.
21-Jan-2015	2	Document status promoted from preliminary to production data.  Updated Section 4: Package mechanical data.
03-Feb-2015	3	Updated title and features in cover page.
03-Oct-2016	4	Updated title and features in cover page.  Updated Table 2: "Absolute maximum ratings" and Table 4: "On/off-states".  Changed Figure 2: "Safe operating area" and Figure 3: "Thermal impedance".

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